# N-Channel 40-V (D-S) MOSFET

# **Key Features:**

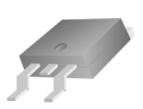
- Low r<sub>DS(on)</sub> trench technology
- · Low thermal impedance
- · Fast switching speed

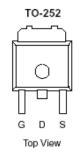
<b>Typical</b>	Applications	
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- White LED boost converters
- Automotive Systems
- Industrial DC/DC Conversion Circuits

PRODUCT SUMMARY				
V <sub>DS</sub> (V)	$r_{DS(on)}(m\Omega)$	I <sub>D</sub> (A)		
40	6 @ V <sub>GS</sub> = 10V	75		
	$8 @ V_{GS} = 4.5V$	65		







ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^{\circ}$ C UNLESS OTHERWISE NOTED)					
Parameter		Symbol	Limit	Units	
Drain-Source Voltage			40	V	
Gate-Source Voltage			±20	V	
Continuous Drain Current a	T <sub>A</sub> =25°C	$I_D$	75	Α	
Pulsed Drain Current <sup>b</sup>		I <sub>DM</sub>	300	^	
Continuous Source Current (Diode Conduction) a			56	А	
Power Dissipation <sup>a</sup>	T <sub>A</sub> =25°C	$P_{D}$	50	W	
Operating Junction and Storage Temperature Range		$T_J, T_{stg}$	-55 to 150	°C	

THERMAL RESISTANCE RATINGS					
Parameter	Symbol	Maximum	Units		
Maximum Junction-to-Ambient <sup>a</sup>	$R_{\theta JA}$	40	°C/W		
Maximum Junction-to-Case	$R_{\theta JC}$	3	C/VV		

1

#### Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

### **Electrical Characteristics**

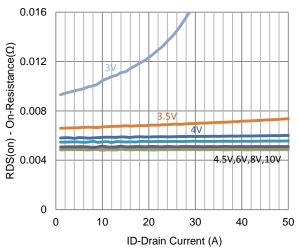
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Static						
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$ , $I_D = 250 \text{ uA}$	1			V
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			±100	nA
Zara Cata Valtaga Drain Current	1	$V_{DS} = 32 \text{ V}, V_{GS} = 0 \text{ V}$			1	uA
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS} = 32 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			25	
On-State Drain Current	I <sub>D(on)</sub>	$V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$	150			Α
Drain-Source On-Resistance	r	$V_{GS} = 10 \text{ V}, I_{D} = 20 \text{ A}$			6	mΩ
Dialii-Source Oil-Resistance	r <sub>DS(on)</sub>	$V_{GS} = 4.5 \text{ V}, I_D = 16 \text{ A}$			8	11122
Forward Transconductance	g <sub>fs</sub>	$V_{DS} = 15 \text{ V}, I_{D} = 20 \text{ A}$		30		S
Diode Forward Voltage	$V_{SD}$	$I_S = 28 \text{ A}, V_{GS} = 0 \text{ V}$		0.83		V
		Dynamic				
Total Gate Charge	$Q_g$	$V_{DS} = 20 \text{ V}, V_{GS} = 4.5 \text{ V},$		65		
Gate-Source Charge	$Q_{gs}$	$I_{DS} = 20 \text{ V}, V_{GS} = 4.3 \text{ V},$ $I_{D} = 20 \text{ A}$		19		nC
Gate-Drain Charge	$Q_gd$	1D = 20 A		29		
Turn-On Delay Time	t <sub>d(on)</sub>	$V_{DS} = 20 \text{ V}, R_{I} = 1 \Omega,$		22		
Rise Time	t <sub>r</sub>	$V_{DS} = 20 \text{ V}, N_L - 1 \Omega,$ $I_D = 20 \text{ A},$		36		no
Turn-Off Delay Time	$t_{d(off)}$	$V_{GEN} = 10 \text{ V}, R_{GEN} = 6 \Omega$		209		ns
Fall Time	t <sub>f</sub>	VGEN = 10 V, NGEN = 0 12		86		
Input Capacitance	C <sub>iss</sub>			8060		
Output Capacitance	C <sub>oss</sub>	$V_{DS} = 15 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$		808		pF
Reverse Transfer Capacitance	$C_{rss}$			783		

#### **Notes**

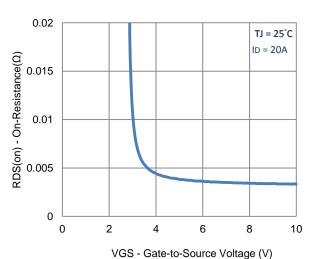
- a. Pulse test: PW <= 300us duty cycle <= 2%.
- b. Guaranteed by design, not subject to production testing.

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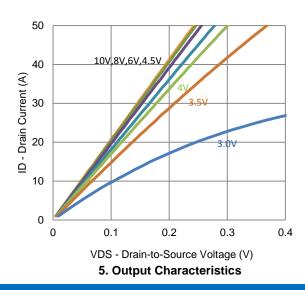
## **Typical Electrical Characteristics**



#### 1. On-Resistance vs. Drain Current



3. On-Resistance vs. Gate-to-Source Voltage



100

TJ = 25°C

80

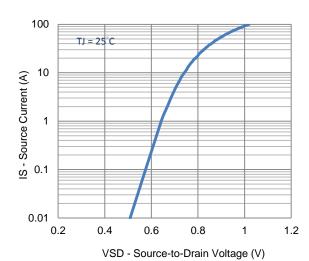
60

20

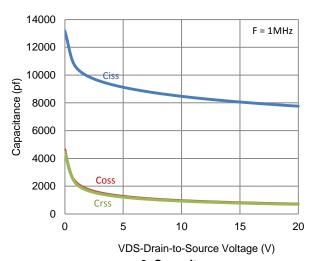
0 1 2 3 4 5

VGS - Gate-to-Source Voltage (V)

2. Transfer Characteristics

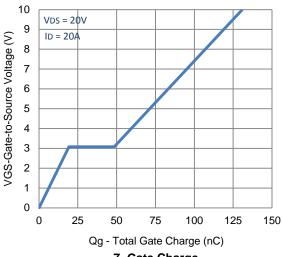


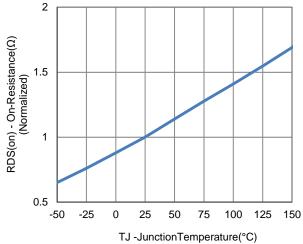
4. Drain-to-Source Forward Voltage



6. Capacitance

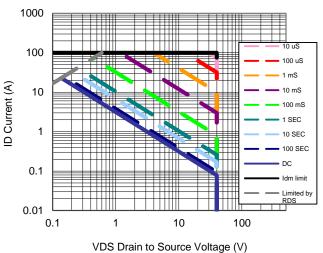
## **Typical Electrical Characteristics**

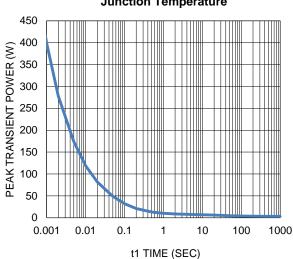




7. Gate Charge

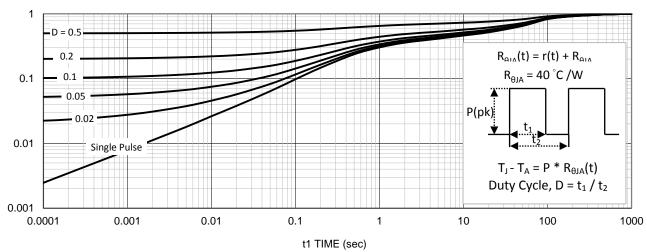






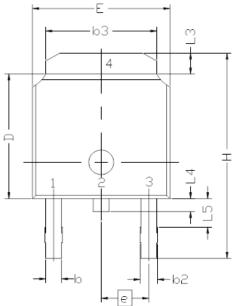
9. Safe Operating Area

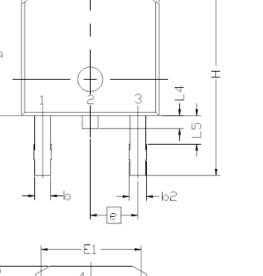
10. Single Pulse Maximum Power Dissipation

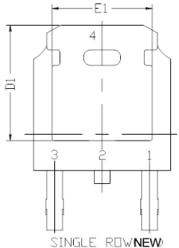


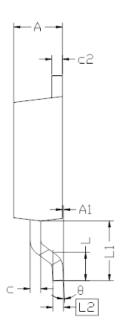
11. Normalized Thermal Transient Junction to Ambient

## **Package Information**









CVADEL	DIMENS:	[DNAL	REQMTS
SYMBOL	MIN	NDM	MAX
E	6.40	6.60	6.731
L	1.40	1.52	1.77
L1	2	.743 R	ĖF
L2	0.	508 BS	
L3	0.89		1.27
L4	0.64		1.01
L5			
D	6.00	6.10	6,223
Н	9.40	10.00	10.40
b	0.64	0.76	0,88
b2	0.77	0.84	1.14
b3	5.21	5.34	5,46
e		286 BS	
I A	2,20	2.30	2,38
A1	0		0.127
_	0.45	0.50	0.60
c2	0.45	0.50	0,58
D1	5,30		
E1	4.40		
θ	0°		10°

### Note:

- 1. All Dimension Are In mm.
- 2. Package Body Sizes Exclude Mold Flash, Protrusion Or Gate Burrs. Mold Flash, Protrusion Or Gate Burrs Shall Not Exceed 0.10 mm Per Side.
- Package Body Sizes Determined At The Outermost Extremes Of The Plastic Body Exclusive Of Mold Flash, Gate Burrs And Interlead Flash, But Including Any Mismatch Between The Top And Bottom Of The Plastic Body.